



2SD1835

Bipolar Transistor 50V, 2A, Low $V_{CE(sat)}$, NPN Single NP

ON Semiconductor®

<http://onsemi.com>

Applications

- Voltage regulators, relay drivers, lamp drivers, electrical equipment

Features

- Adoption of FBET, MBIT processes
- Low collector-to-emitter saturation voltage
- Large current capacity
- Fast switching time

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

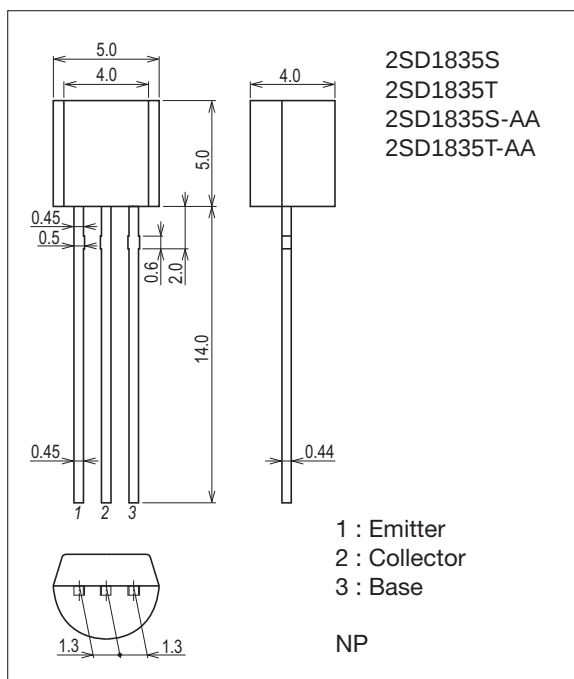
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		60	V
Collector-to-Emitter Voltage	V_{CEO}		50	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		2	A
Collector Current (Pulse)	I_{CP}		3	A
Collector Dissipation	P_C		0.75	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

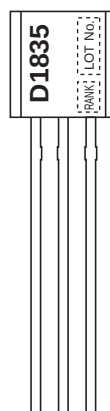
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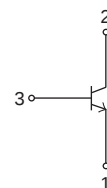
Product & Package Information

- Package : NP
- JEITA, JEDEC : SC-34A, TO-92, TO-226AA, SOT-54
- Minimum Packing Quantity : 1,500 pcs./box, 500pcs./bag

Marking



Electrical Connection



2SD1835

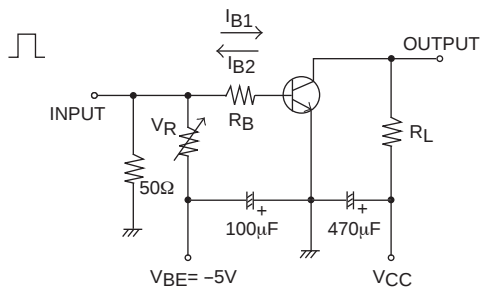
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=50V, I_E=0A$			100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4V, I_C=0A$			100	nA
DC Current Gain	h_{FE1}	$V_{CE}=2V, I_C=100mA$	100*		560*	
	h_{FE2}	$V_{CE}=2V, I_C=1.5A$	40			
Gain-Bandwidth Product	f_T	$V_{CE}=10V, I_C=50mA$		150		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		12		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1A, I_B=50mA$		0.15	0.4	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1A, I_B=50mA$		0.9	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		60		ns
Storage Time	t_{stg}			550		ns
Fall Time	t_f			30		ns

* : The 2SD1835 is classified by 100mA h_{FE} as follows :

Rank	R	S	T	U
h_{FE}	100 to 200	140 to 280	200 to 400	280 to 560

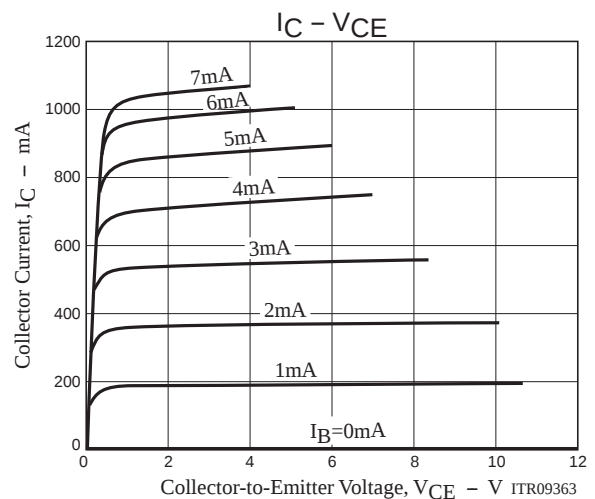
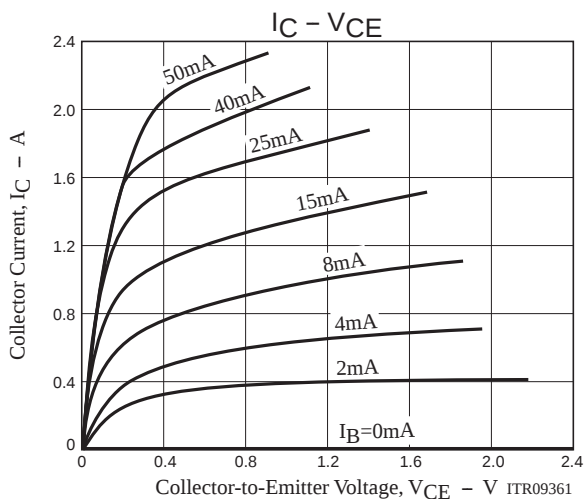
Switching Time Test Circuit

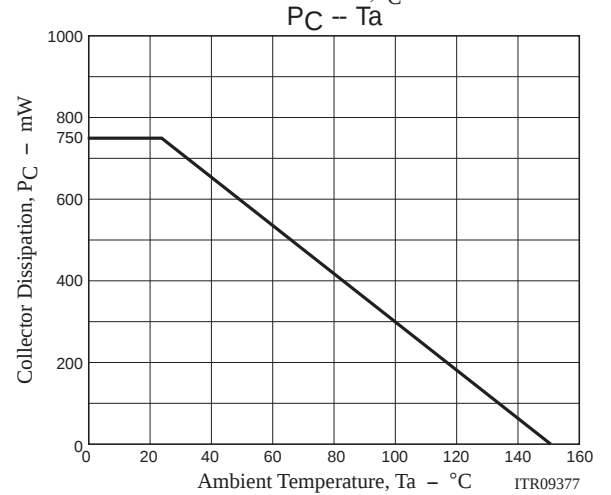
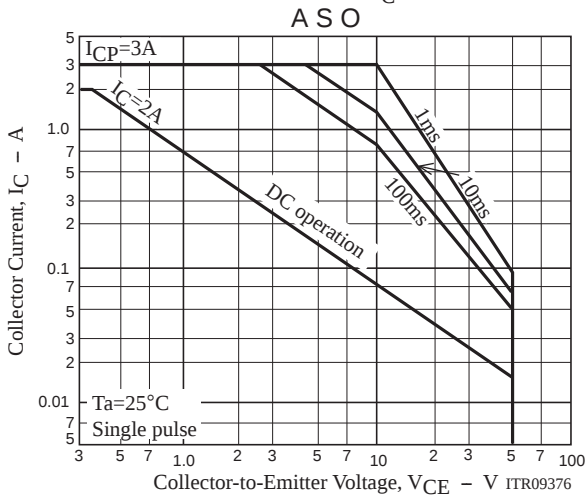
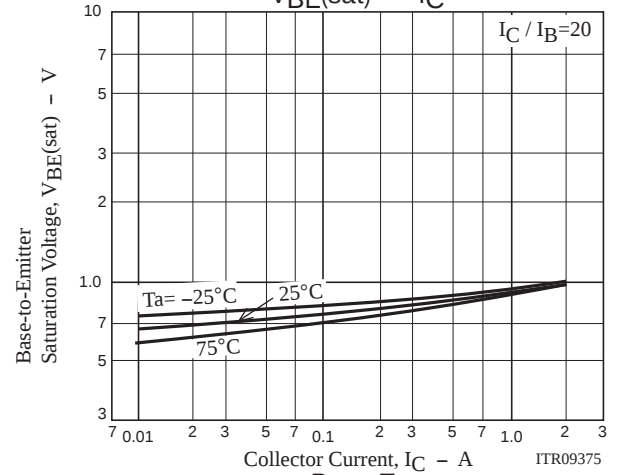
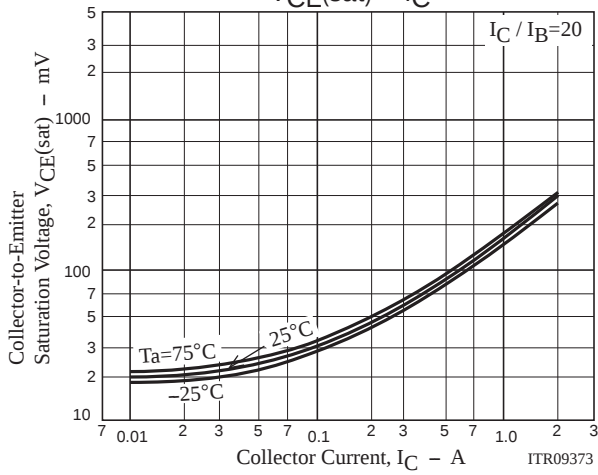
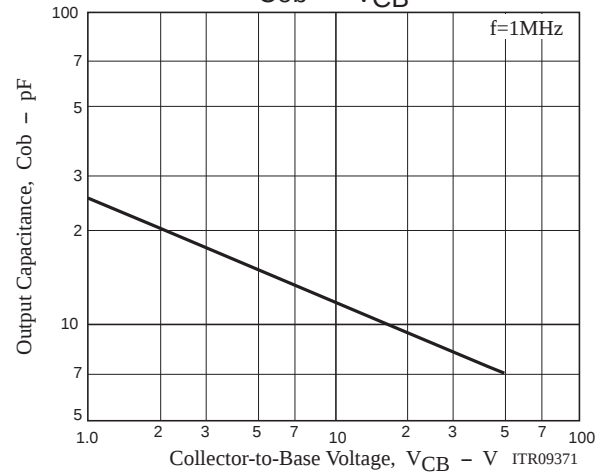
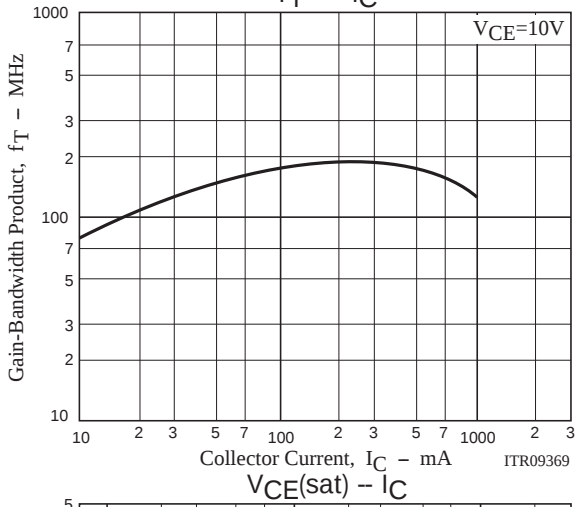
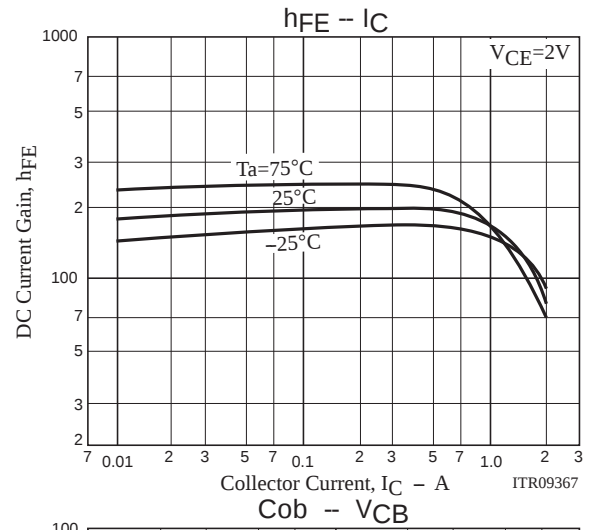
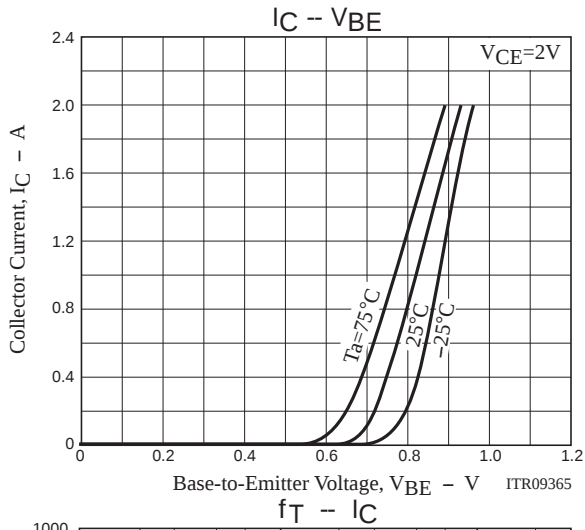


$$I_C = 10I_{B1} = -10I_{B2} = 500mA, V_{CC} = 25V$$

Ordering Information

Device	Package	Shipping	memo
2SD1835S	NP	500pcs./bag	Pb Free
2SD1835T	NP	500pcs./bag	
2SD1835S-AA	NP	1,500pcs./box	
2SD1835T-AA	NP	1,500pcs./box	





Taping Specification

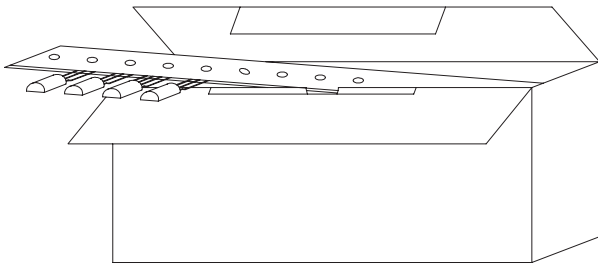
2SD1835S-AA, 2SD1835T-AA

1. Packing Format

Package Name	Packing Type	Maximum Number of devices contained (pcs)		Packing format
		Inner BOX (C-2)	number of contained	
N P	A A	Dimensions:mm (external) 330×45×145	1,500	Outer BOX (C-6) 16 inner boxes contained (24,000pcs) Dimensions:mm (external) 585×345×200

Packing method

Put zigzag folding in an inner box.

Inner box label

(unit:mm)

Type No. →

LOT No. →

Quantity →

Origin →

69		43
(P) TYPE	0000000000	
(1) LOT	00	
(Q) QTY	0,000 (1) LEAD FREE *	
(Z) SPECIAL	*Z0722005310C*	
ASSEMBLY:**** (DIFFUSION:****)		

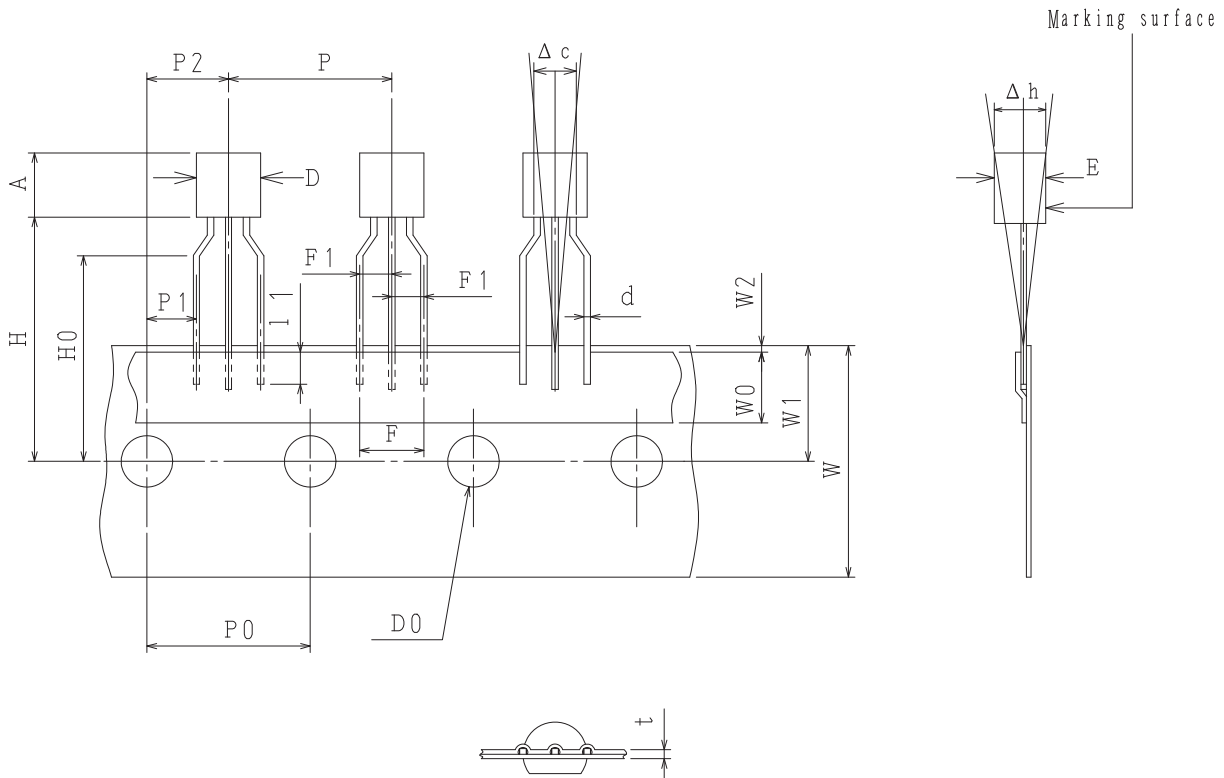
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping specifications

2-1. Carrier tape size



2-2. Taping size standard

unit:mm

Item	Symbol	Standard	Tolerance	Item	Symbol	Standard	Tolerance
Work piece outside diameter	D	5.0	±0.2	Tape width	W	18.0	+1.0 -0.5
	E	4.0	±0.2	Adhesive tape	W0	6.0	±1.5
Work piece height	A	5.0	±0.2	Displacement of perforations	W1	9.0	±0.5
Lead wire diameter	d	0.45×0.44t	±0.1	Work piece bottom surface position	H	19.0	±1.0
Bonded lead wire	l1	2.0MIN		Insert stopper position	H0	16.0	±0.5
Pitch between products	P	12.7	±0.5	Work piece upper limit position	H1	24.5	±1.5
Pitch between perforations	P0	12.7	±0.2	Perforations diameter	D0	φ4.0	±0.2
Distance between lead wire	F	5.0	+0.8 -0.2	Tape thickness	t	0.6	±0.2
Lead wire pitch distance	F1	2.5	+0.2 -0.1	Product inclination	Δc	0	±1.0
Product inclination	Δh	0	±2.0	Measurement position is the bottom of the clinch			
Displacement of perforations	P1	3.85	±0.3				
	P2	6.35	±0.3	Not to be displaced to the outside of the board			
Displacement of tape	W2	0.5MAX					

Bag Packing Specification

2SD1835S, 2SD1835T

1 . Packing condition

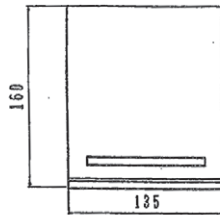
Storage package outline name	Maximum number of devices contained (pcs.)		Packing condition	
	Bags	Inner box	Outer box (A-1)	Outer box (A-2)
NP	500	B-1 Inner box dimensions : mm (external) 445×225×55	Devices contained 10,000 5 inner boxes contained 50,000 Outer box dimensions : mm (external) 470 × 250 × 300	3 inner boxes contained 30,000 Outer box dimensions : mm (external) 470 × 250 × 190

3. Bar code label

(Unit : mm)

2. Bag dimensions

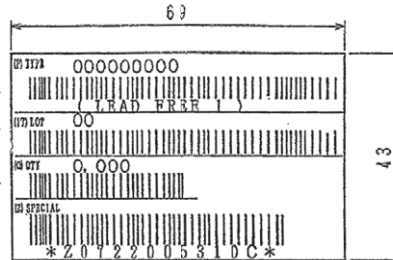
(Unit : mm)



Type No. →

Lot No. →

Quantity →

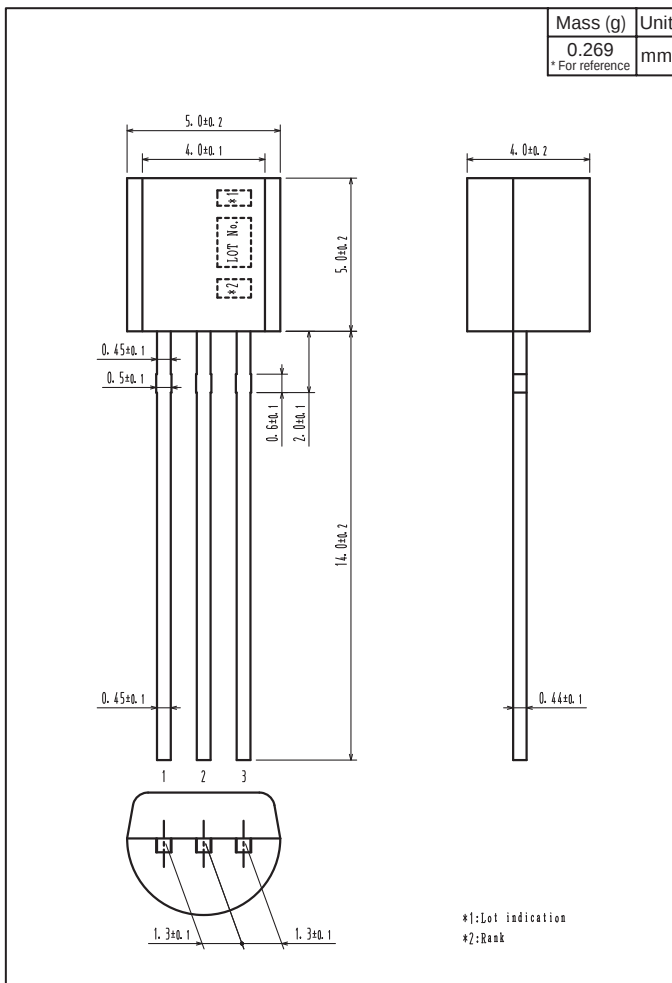


* LEAD FREE 1 :

Lead-free External terminal surface treatment product.

Outline Drawing

2SD1835S, 2SD1835T



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